Photodetectors

Туре	Construction		Typ. Peak Spectral	Max. Power	Diode Rev.	Transistor Max. Ratings			Typical Light Current		Typical Dark Curren t		Case	Lead	Man.
	Constr	<u></u>	Response (nm)	Diss. (mW)	Volts (V)	V _{CB0}	V _{CEO}	V _{EBO} (V)	μΑ	at V _{CE}	пА	at V _{CE}	Outline	Info.	Figure
LS616	Si	11		50					E0	5	25	70		127	77
LS617	Si	11	-	50 50	-	_	-	-	5mA 6mA	5	25 25	30 30	-	127	TI TI
LS618	Si	11	_	50	_		-	-	7mA	5	25 25	30	-	127	TI
LS6 19	Si	31	_	50	_	_		_	8mA	5	25	30	_	127	TI
MAL 100	Si	n	_	200	-	50	30	-	200	5	100	5	-	05	n .
MEL31	Si	n	_	200	_	40	30	_	10	5	50	5	TO-106	05	u
MEL32	Si	n	_	200	-	60	40	_	30	5	50	5	TO-106	05	и
MEL 100	Si	11	-	200	-	50	30	-	200	5	100	5	TO-106	05	ш
MEPT 100	Si	a	-	200	-	50	30	_	200	5	100	5	TO-106	05	ш
MEPT 100A	51	n	-	200	-	50	30	-	1r•A	5	100	5	TO-106	05	u
MEPT1008	Si	н	-	200	-	50	30	-	1.3mA		100	5	TO-106	133	и
MRD 160	Si	n	800	-	-	40	48	-	1.5mA		100	20	-	-	Ma
MRD300	Si	11	800	-	-	50	50	-	7.5mA		25	20	-	-	Mo
MRD310	Si	11	800	-	-	50	50	-	2.5mA		25	20	-	-	Mo
MRD450	5 i	.,	800	-	-	40	40	-	4mA	-	100	20	-	-	Mo
MRD500	Si	"	800	-	100	_	_	-	9	-	2	20	-	-	Mo
MRD510	51	"	800	-	100	-	-	_	2	_	2	20	-	-	Mo
MRD601	Si	#	800	-	-	50	50	_	1.5mA		2 5	30	-	-	Mo
MRD602	5 i		800	-	-	50	50	-	3.5mA	٠.	25	30	-	-	Mo
MRD603	5 i	11	800	-	-	50	50	-	6mA	-	25	30	-	-	MO
MRD604	Si	11	800	-	-	50	50	-	8.5mA	-	25	30	_	-	Mo
MRD3050	Si	#	800	-	-	30	30	_	200	-	100	20	_	_	Mo
MRD3051	Si	m m	800	-	-	30	30	-	200	-	100	20	-	-	Mo
MRD3054	Si	m m	800	-	-	30	30	-	1.8mA		100	20	-	-	Mo
MRD3055	Si	Ħ	800	-	-	30	30	-	2.5mA	-	100	20	-	-	Mo
MRD3056	Si	n	800	-	-	30	30	-	1.2mA		100	20	-	-	Mo
TIL63	Si	"	-	50	-	-	-	-	400	5	25	30	-	-	TI
TIL64	Si	н	-	50	-	-	-	-	400	5	25	30	-	-	TI
TIL65	51	"	-	50	-	-	-	-	1mA	5	25	30	_	-	TI
TIL66	Si.	"	-	50	-	-	-	-	2.5mA	5	25	30	-	-	TI
TIL67	Si	#	-	50	-	-	-	-	6mA	5	25	30	-	-	TI
TIL78	Si	11	-	50	-	-	-	-	1mA	5	25	30	-	-	TI
TIL81	Si	n	-	250	-	-	-	-	5mA	5	100	10	-	-	ΤI
TIL99	Si	n	-	250	-	-	-	-	1mA	5	100	10	-	-	TI
TIL401	Si	11	-	50	-	-	-	-	500	50	25	30	-	-	TI
TIL402	Si	u u	_	50	-	_	_	_	2mA	5	25	30	-	_	ΥI
TIL403	Si	U	-	50	_	-	_	_	5mA	5	25	30	_	_	TI
TIL404	Si	IJ	-	50	-	-	_	-	8mA	5	25	30	_	_	ΤĪ
TIL405	Si	u	-	50	-	-	-	-	10mA	5	25	30	_	_	TI
ZM100	Si NPN	11	780	300	-	35	35	10	-	-	1 _u A	10	TO-18	05	Fe
2M44D	C. NC.		70 7	700		75		_						_	_
ZM110 2N5777	Si NPN	Transisto "	r 780 800	300	-	35	35	5	-	_	25	10	TO-18	05	Fe
2N5777 2N5778				200	-	25 4.0	25	8	500	5	100	12	-	09	GE
2N5778 2N5779	Si NPN Si NPN		800 800	200 200	_	40 25	40 25	12 8	500	5 5	100	12	-	09	GE
2N5779	Si NPN	 D	800	200	-	40	40	8 12	2mA 2mA	5 5	100 100	12 12	-	09 09	GE GE
2,45,00	OT MUM			200	-	40	40	12	ZIIIM	٥	טטי	12	-	UZ	DE